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5962-E1098-2

1.	SCOPE					
with 1	Scope. This drawing des 2.1 of MIL-STD-883, "Pro N devices".	cribes device requi visions for the use	rements fo of MIL-S	or class B microc TD-883 in conjunct	ircuits in accordance tion with compliant	<u> </u>
1.2	Part number. The comple	te part number shal	be as st	nown in the follow	ving example:	
	5962-87730	01	*	E     	<u> </u>	
	Drawing number	Device type (1.2.1)	Case (1	outline	Lead finish per MIL-M-38510	
1.2.	1 Device type. The devi	ce type shall identi	ify the ci	rcuit function as	follows:	
	Device type	Generic number		Circuit function	<u>1</u>	
	01	10H521	4 wide	OR-AND/OR-AND-IN	IVERT gate	
1.2. as fol	2 <u>Case outlines</u> . The cas lows:	se outlines shall be	e as desig	gnated in appendix	c C of MIL-M-38510, a	ınd
<u>o</u>	utline letter			Case	outline	
	F	D-2 (16-lead, .840* F-5 (16-lead, .440" C-2 (20-terminal, .	x .285	x.085"), flat pac	n-line package kage are chip carrier pac	:kage
1.3	Absolute maximum ratings.					
	Supply voltage range (VEE Input voltage range Storage temperature range Lead temperature (solderi Junction temperature (TJ) Maximum power dissipation Thermal resistance, junct	ng, 10 seconds) -		-5.2 V dc to 0.0 -65°C to +165°C +300°C	V dc	
1.4	Recommended operating con	ditions.				
	Supply voltage range ( $Y_{EE}$ Supply voltage range ( $Y_{CC}$	}		-5.46 V dc minim -0.02 V dc to +0 +1.98 V dc to	um to -4.94 V dc max .02 V dc or +2.02 V dc	imum
	Ambient operating tempera Minimum high level input $T_A = +25^{\circ}C$ $T_A = +125^{\circ}C$ $T_A = -55^{\circ}C$ Maximum low level input v	ture range (T <sub>A</sub> ) - voltage (V <sub>IH</sub> ): oltage (V <sub>IL</sub> )		-55°C +0 +125°C		

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## 2. APPLICABLE DOCUMENTS

2.1 Government specification and standard. Unless otherwise specified, the following specification and standard, of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein.

SPECIFICATION

MILITARY

MIL-M-38510 - Microcircuits, General Specification for.

STANDARD

**MILITARY** 

MIL-STD-883 - Test Methods and Procedures for Microelectronics.

(Copies of the specification and standard required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity.)

- 2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence.
  - 3. REQUIREMENTS
- 3.1 <u>Item requirements</u>. The individual item requirements shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein.
- 3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-M-38510 and herein.
  - 3.2.1 Terminal connections. The terminal connections shall be as specified on figure 1.
  - 3.2.2 Truth table. The truth table shall be as specified on figure 2.
  - 3.2.3 Logic diagram. The logic diagram shall be as specified on figure 3.
- 3.2.4 Test circuit and switching waveforms. The test circuit and switching waveforms shall be as specified on figure 4.
  - 3.2.5 Case outlines. The case outlines shall be in accordance with 1.2.2 herein.
- 3.3 Electrical performance characteristics. Unless otherwise specified, the electrical performance characteristics are as specified in table I and apply over the full ambient operating temperature range.
- 3.4 Marking. Marking shall be in accordance with MIL-STD-883 (see 3.1 herein). The part shall be marked with the part number listed in 1.2 herein. In addition, the manufacturer's part number may also be marked as listed in 6.4 herein.
- 3.5 Certificate of compliance. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in 6.4. The certificate of compliance submitted to DESC-ECS prior to listing as an approved source of supply shall state that the manufacturer's product meets the requirements of MIL-STD-883 (see 3.1 herein) and the requirements herein.

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TABLE I. Electrical performance characteristics. Conditions  $-55^{\circ}C < T_A < +125^{\circ}C$  unless otherwise specified Symbol Limits Unit Test Group A subgroups Min Max Cases E, F, and 2 Quiescent tests 1/  $v_{\text{IH}}$ VIL High level output voltage | VOH |Outputs terminated| through 100Ω to -2 V 1-0.780 |-1.950 |-1.010 |-0.780 | ٧ | VCC = 0.0 V |-1.950 1-0.650 2 |-0.860 |-0.650 | | VEE = -5.2 V |-0.840 |-1.950 I-1.060 I-0.840 2/ |-0.780 |-1.950 |-0.650 |-1.950 |-1.950 |-1.580 Low level output voltage VOL 2 |-1.950 |-1.565 -0.840 |-1.950 3 |-1.950 |-1.610 High level threshold VOHA |-1.110 |-1.480 -1.010 -0.780 output voltage -0.960 |-1.465 |-0.860 |-0.650 -1.060 |-0.840 -1.160 |-1.510 3 Low level threshold I V<sub>OLA</sub> -1.950 |-1.580 |-1.110 |-1.480 1 output voltage |-0.960 |-1.465 2 |-1.950 |-1.565 |-1.160 |-1.510 3 -1.950 |-1.610 VEE = -5.46 V Power supply drain current| IFE -26 -29 mΑ VCC = 0.0 V VIH = -0.780 V at +25°C 2, 3 -0.650 V at +125°C -0.840 V at -55°C High level input current All inputs 295 I<sub>IH1</sub> 1, 2 except A 500 μΑ Input A 360 I<sub>IH2</sub> 1, 2 610 V<sub>EE</sub> = -4.94 V V<sub>IL</sub> = -1.950 V V<sub>CC</sub> = 0.0 V Low level input current 1, 3 0.5 0.3 μΑ 3/ IIL Functional tests See 4.3.1c 7, 8 See footnotes at end of table. **STANDARDIZED** SIZE Α 5962-87730 MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER **REVISION LEVEL** SHEET DAYTON, OHIO 45444 4

TABLE I.	Elect	rical	performance c	haracter	istics -	Continued	•		
Test	  Symbol 	     -	Conditi 55°C < TA < † less otherwis	·125°C	ied	  Group A  subgroups 		mits     Max	  Unit 
Cases E and F	<u>'                                    </u>		DC rapid tes			•	<u> </u>		<u> </u>
High level output voltage	I V <sub>OH</sub>	throu  100Ω  V <sub>CC</sub> =	ts terminated gh to -2 V 0.0 V -5.2 V	1		 	  -1.017  -0.867  -1.067	1-0.658	 
Low level output voltage	V <sub>OL</sub>	 	<u>2</u> /	-0.787  -0.638  -0.848	1-1.950		  -1.950  -1.950  -1.950	-1.567	V
High level threshold output voltage	V <sub>OHA</sub>	 		-1.097  -0.967  -1.167	-1.467	į 2	:	-0.787  -0.658  -0.848	<b>γ</b>
Low level threshold output voltage	V <sub>OLA</sub>	   		  -1.097  -0.967  -1.167	-1.467		-1.950  -1.950  -1.950	-1.567	v 
Power supply drain current $\frac{3}{2}$	IEE	1Vcc =	-5.46 V 0.0 V -0.780 V at -0.650 V at -0.840 V at	+125°C		1 2,3	   -25   -28		mA   
High level input current	I IH1	     		All in except		1, 2 3		280 485	!     μΑ
	I IH2			Input	A	1, 2 3		345 595	
Low level input current	IIL	V   =	-4.94 V -1.950 V 0.0 V	<u>3</u> /		1, 3 2	0.5 0.3		μ <b>Α</b>
Functional tests		See 4	1.3.1c			7, 8			   
See footnotes at end of table.									
STANDARDIZEI MILITARY DRAW			SIZE A			Ę	5962-877	30	
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TABLE I. Electrical performance characteristics - Continued. Group A Unit Conditions -55°C < TA < +125°C unless otherwise specified Limits Test Symbol subgroups Min Max DC rapid tests 4/ Case 2 ٧IH ٧IL High level output voltage | VOH |Outputs terminated| through ٧ |-1.021 |-0.792 100Ω to -2 V -0.792 |-1.950 V<sub>CC</sub> = 0.0 V V<sub>EE</sub> = -5.2 V |-0.872 |-0.663 |-1.072 |-0.853 2 -0.643 |-1.950 -0.853 |-1.950 2/ |-0.792 |-1.950 |-1.950 |-1.584 ٧ 1 Low level output voltage IVOL -0.643 |-1.950 |-1.950 |-1.569 2 |-1.950 |-1.614 |-0.853 |-1.950 3 ٧ 1 |-1.021 |-0.792 | High level threshold |-1.101 |-1.484 VOHA |-0.972 |-1.469 2 |-0.872 |-0.663 output voltage 3 -1.172 |-1.514 |-1.072 |-0.853 | -1.101 |-1.484 1 |-1.950 |-1.584 ٧ Low level threshold VOLA -0.972 |-1.469 2 |-1.950 |-1.569 output voltage |-1.172 |-1.514 3 |-1.950 |-1.614 | V<sub>EE</sub> = -5.46 V | V<sub>CC</sub> = 0.0 V | V<sub>IH</sub> = -0.780 V at +25°C -25 -28 mΑ 1 Power supply drain current|IEE 2, 3 3/ -0.650 V at +125°C -0.840 V at -55°C 1, 2 280 High level input current All inputs I IH1 except A 485 μА 345 I IH2 Input A 1, 2 595 | VEE = -4.94 V | VIL = -1.950 V  $\mu \boldsymbol{A}$ IIL 1,3 0.5 0.3 Low level input current 3/ | VCC = 0.0 V See 4.3.1c 7, 8 Functional tests See footnotes at end of table. SIZE **STANDARDIZED** Α 5962-87730 MILITARY DRAWING **DEFENSE ELECTRONICS SUPPLY CENTER** REVISION LEVEL SHEET 6 DAYTON, OHIO 45444

Test	Symbol Symbol	Conditions	Group A	Limits		Unit	
		-55°C < TA < +125°C   unless otherwise specified	subgroups  	Min	Max	<u>!</u>	
Cases E, F, and 2		AC tests					
Transition time	t <sub>TLH</sub> ,	V <sub>EE</sub> = -2.94 V   V <sub>CC</sub> = 2.0 V   C <sub>L</sub> ≤ 5 pF	9 10 11	0.50 0.50 0.50	1.80   2.10   1.70	ns	
Propagation delay time, input A to Y	tpLH1, tpHL1, tpLL1,	Lōad all outputs through 100Ω   to ground   See figure 4   	9 10 11	0.45 0.55 0.45	1.80   2.40   1.80	   ns     	
Propagation delay time, all inputs except A to Y	tpLH2, tpHL2, tpLL2,		9 10 11	0.60 0.70 0.55	2.00 2.60 2.00	ns	

- 1/ The quiescent limits are determined after a device has reached thermal equilibrium. This is defined as the reading taken with the device in a socket with > 500 LFPM of +25°C, +125°C or -55°C (as applicable) air blowing on the unit in a transverse direction with power applied for at least 4 minutes before the reading is taken. This method was used for theoretical limit establishment only. All devices shall be tested to the delta V (rapid test) conditions specified herein. The rapid test method is an equivalent method of testing quiescent conditions.
- $\frac{2}{}$  The high and low level output current varies with temperature, and shall be calculated using the following formulas:  $I_{OH}$  = (V<sub>OH</sub> 2 V)/100 $\Omega$   $_{IOL}$  = (V<sub>OL</sub> 2 V)/100 $\Omega$  .
- 3/ The  $I_{\mbox{\scriptsize FE}}$  and  $I_{\mbox{\scriptsize IL}}$  limits, although specified in the minimum column, shall not be exceeded, in magnitude, as a maximum value.
- 4/ The dc rapid test forcing functions and limits are used for all dc testing. These limits are determined for each device type based on the power dissipation and package type. The rapid test (delta V) limits and forcing functions are skewed allowing rapid testing to be performed at standard temperatures without the addition of delta T's.

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- 3.6 Certificate of conformance. A certificate of conformance as required in MIL-STD-883 (see 3.1 herein) shall be provided with each lot of microcircuits delivered to this drawing.
- 3.7 Notification of change. Notification of change to DESC-ECS shall be required in accordance with MIL-SID-883 (see 3.1 herein).
- 3.8 Verification and review. DESC, DESC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.
  - 4. OUALITY ASSURANCE PROVISIONS
- 4.1 Sampling and inspection. Sampling and inspection procedures shall be in accordance with section 4 of MIL-N-38510 to the extent specified in MIL-STD-883 (see 3.1 herein).
- 4.2 <u>Screening.</u> Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:
  - a. Burn-in test, method 1015 of MIL-STD-883.
    - (1) Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.5 herein).
    - (2)  $T_A = +125^{\circ}C$ , minimum.
  - b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.
- 4.3 Quality conformance inspection. Quality conformance inspection shall be in accordance with method 5005 of MIL-STD-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.
  - 4.3.1 Group A inspection.
    - a. Tests shall be as specified in table II herein.
    - b. Subgroups 4, 5, and 6 in table I, method 5005 of MIL-STD-883 shall be omitted.
    - c. Subgroups 7 and 8 tests shall verify the truth table specified on figure 2 herein.
  - 4.3.2 Groups C and D inspections.
    - a. End-point electrical parameters shall be as specified in table II herein.
    - b. Steady-state life test conditions, method 1005 of MIL-STD-883.
      - Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.5 herein).
      - (2)  $T_A = +125^{\circ}C$ , minimum.
      - (3) Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

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Case outlines	E E	F	2
Terminal number	   Terr	ninal sym	nbol
1	V <sub>CC1</sub>	D2	NC
2	Y	E2	V <sub>CC1</sub>
3	<b>₩</b>	F2	Y
4	F1	V <sub>CC2</sub>	▼
5	E1	V <sub>CC1</sub>	F1
6	D1	Υ	NC
7	C1	₹	E1
8	I V <sub>EE</sub>	F1	D1
9	B1	E1	C1
10	ļ a	D1	V <sub>EE</sub>
11	B2	C1	NC
12	C2	i V <sub>EE</sub>	B1
13	D2	B1	
14	E2	<b>A</b>	B2
15	F2	   B2	C2
16	V <sub>CC2</sub>	   C2	I NC I
17			D2
18			E2
19		 	F2
20 		   	V <sub>CC2</sub>

NC = No connection

FIGURE 1. Terminal connections.

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		Inp	uts	;		Out	puts
i A	В	С	D	E	F	Y	Y
	L X					L   L   L	H
		l o bin				Н	L

H = High level voltage
L = Low level voltage
X = Irrelevant

FIGURE 2. Truth table.

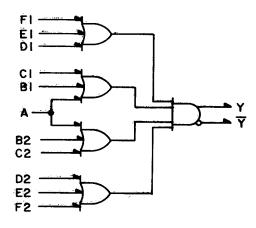
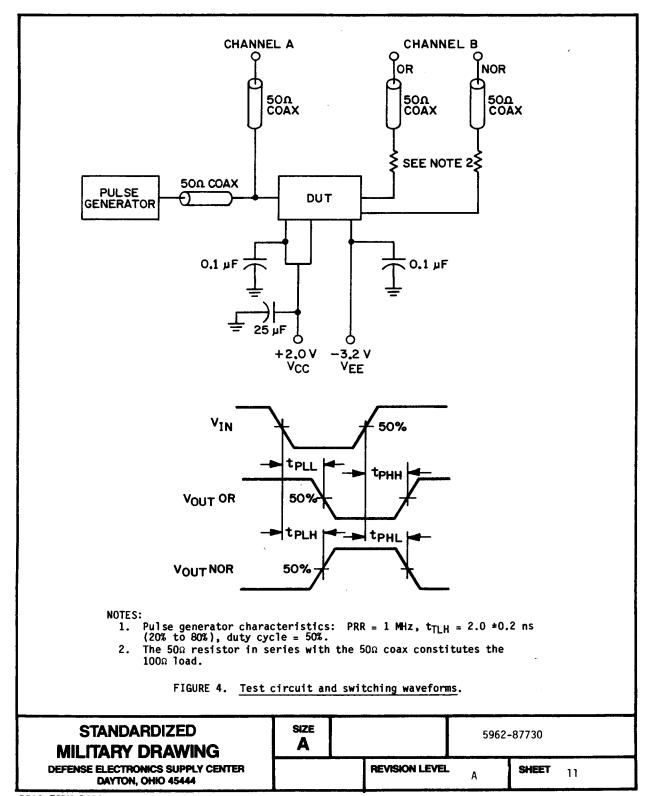


FIGURE 3. Logic diagram.

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## TABLE II. Electrical test requirements.

MIL-STD-883 test requirements	Subgroups   (per method   5005, table I)
Interim electrical parameters (method 5004)	1
Final electrical test parameters (method 5004)	   1*, 2, 3, 7, 8,   9
Group A test requirements (method 5005)	   1, 2, 3, 7, 8,   9, 10, 11
Groups C and D end-point electrical parameters (method 5005)	1, 2, 3

\* PDA applies to subgroups 1.

## 5. PACKAGING

 $5.1\,$  Packaging requirements. The requirements for packaging shall be in accordance with MIL-M-38510.

## 6. NOTES

- 6.1 <u>Intended use</u>. Microcircuits conforming to this drawing are intended for use when military specifications do not exist and qualified military devices that will perform the required function are not available for OEM application. When a military specification exists and the product covered by this drawing has been qualified for listing on QPL-38510, the device specified herein will be inactivated and will not be used for new design. The QPL-38510 product shall be the preferred item for all applications.
- 6.2 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.
- 6.3 Comments. Comments on this drawing should be directed to DESC-ECS, Dayton, Ohio 45444, or telephone 513-296-5375.

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6.4 Approved source of supply. An approved source of supply is listed herein. Additional sources will be added as they become available. The vendor listed herein has agreed to this drawing and a certificate of compliance (see 3.5 herein) has been submitted to DESC-ECS.

Military drawing part number	Vendor     CAGE     number	Vendor <u>l/</u> similar pa <del>r</del> t number
5962-8773001EX	04713	10H521/BEAJC
5962-8773001FX	04713	10H521/BFAJC
5962-87730012X	04713	10H521M/B2AJC

1/ Caution. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

Vendor CAGE number

04713

Vendor name and address

Motorola, Incorporated 7402 South Price Road Tempe, AZ 85283

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